Peak Reducing EMI Solution

Features

- Generates an EMI optimized clocking signal at the output.
- Selectable output frequency range.
- Single 1.25% or 2.4% down spread output.
- Integrated loop filter components.
- Operates with a 3.3V supply.
- Low-power CMOS design.
- Available in 8-pin SOIC and 8-pin TSSOP packages.

Product Description

The AS80M2180 is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The AS80M2180 reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of down stream clock and data dependent signals. The AS80M2180 allows significant system cost savings by reducing the number of circuit board layers and shielding that are traditionally required to pass EMI regulations.

The AS80M2180 modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, thereby decreasing the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most clock generators. Lowering EMI by increasing a signal's bandwidth is called spread spectrum clock generation.

The AS80M2180 uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all-digital method.

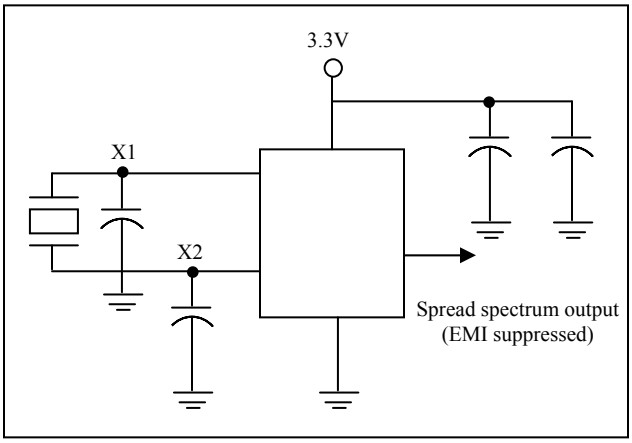
Applications

The AS80M2180 is targeted towards notebook LCD displays, other displays using an LVDS interface, PC peripheral devices and embedded systems.

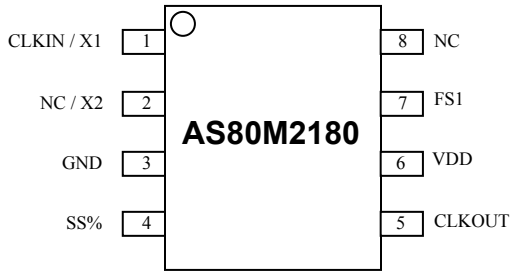
Key Specifications

Description	Specification
Supply voltages	V_{DD} = 3.3V ± 5%
Frequency range	6 MHz ≤ 30 MHz
Cycle-to-cycle jitter	325 ps (typical)
Selectable spread percentage	-1.25% or –2.4%
Output duty cycle	40/60% (worst case)
Output rise and fall time	5ns (maximum)

Simplified Block Diagram



Pin Diagram



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Modulation Width Selection

SS%	Output
0	FIN ≥ FOUT ≥ FIN – 1.25%
1	FIN ≥ FOUT ≥ FIN – 2.4%

Frequency Range Selection

FS1	Modulation Rate
0	6 ≤ FIN ≤10
1	18 ≤ FIN ≤ 30

Pin Description

Pin#	Pin Name	Type	Description
1	CLKIN or X1	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected to either an external crystal or an external reference clock.
2	NC OR X2	O	Crystal connection. Connection for an external crystal. If using an external reference, this pin must be left unconnected.
3	GND	G	Ground to entire chip.
4	SS%	I	Modulation width selection. When spread spectrum feature is turned on, this pin is used to select the amount of variation and peak EMI reduction that is desired on the output signal. Internal pull-up resistor.
5	CLKOUT	O	Output modulated frequency. Copy of the un-modulated input clock.
6	VDD	P	Power supply for the entire chip (3.3V).
7	FS1	I	Frequency selection bit 1. This pin selects the frequency range of operation. (*Refer to the Frequency Range Selection Table*). This pin has an internal pull-up resistor.
8	NC	-	No connect.

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
V_{DD}, V_{IN}	Voltage on any pin with respect to GND	-0.5 to + 7.0	V
T_{STG}	Storage temperature	-65 to +125	°C
T_A	Operating temperature	0 to 70	°C
Note: These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.			

DC Electrical Characteristics

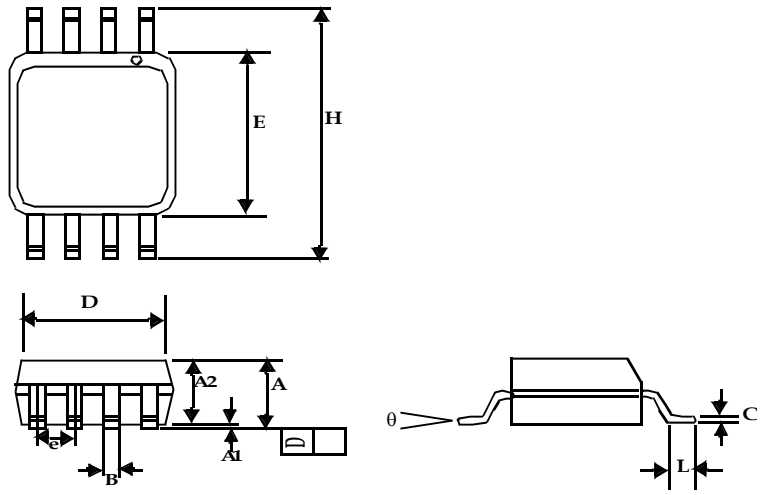
Symbol	Parameter	Min	Typ	Max	Unit
V_{IL}	Input low voltage	GND – 0.3	-	0.8	V
V_{IH}	Input high voltage	2.0	-	V_{DD} + 0.3	V
I_{IL}	Input low current (pull-up resistors on inputs SS%, FS1)	-	-	-27	µA
I_{IH}	Input high current	-	-	18	µA
I_{XOL}	X_{OUT} output low current (@ 0.4V, V_{DD} = 3.3V)	-	3	-	mA
I_{XOH}	X_{OUT} output high current (@2.5V, V_{DD} = 3.3V)	-	4	-	mA
V_{OL}	Output low voltage (V_{DD} = 3.3V, I_{OL} = 4mA)	-	-	0.4	V
V_{OH}	Output high voltage (V_{DD} = 3.3V, I_{OH} = 4mA)	2.5	-	-	V
I_{CC}	Dynamic supply current normal mode (3.3V and 10pF loading)	8	21	35	mA
I_{DD}	Static supply current standby mode	-	0.8	-	µA
V_{DD}	Operating voltage	2.8	3.3	3.7	V
t_{ON}	Power up time (first locked clock cycle after power up)	-	0.18	-	mS
Z_{OUT}	Clock output impedance	-	50	-	Ω

AC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Unit
CLKIN	Input frequency	6	-	30	MHz
CLKOUT	Output frequency	6	-	30	MHz
t_{LH}*	Output rise time (measured at 0.8V to 2.0V)	1.2	1.3	1.4	ns
t_{HL}*	Output fall time (measured at 2.0V to 0.8V)	0.8	0.9	1.0	ns
t_{JC}	Jitter (cycle to cycle)	-	-	325	ps
t_D	Output duty cycle	45	50	55	%
*t_{LH} and t_{HL} are measured into a capacitive load of 15pF					

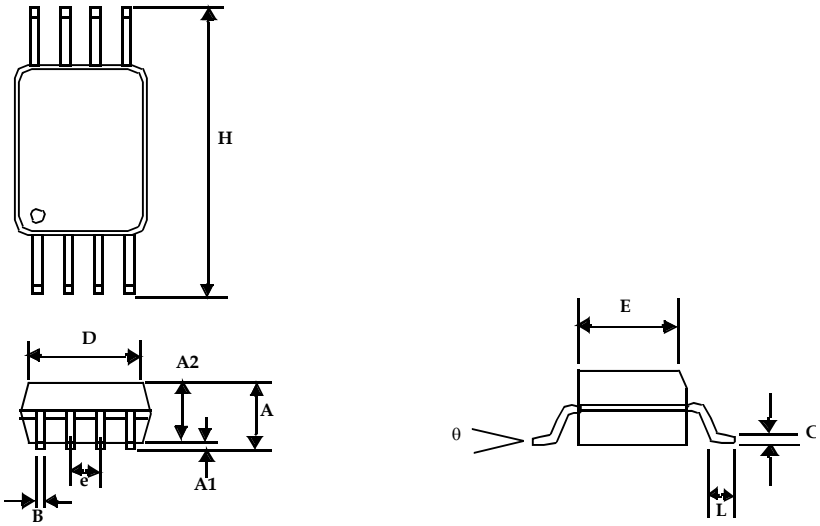
Package Information:

8-Pin SOIC



Symbol	Dimensions in inches		Dimensions in millimeters	
	Min	Max	Min	Max
A	0.057	0.071	1.45	1.80
A1	0.004	0.010	0.10	0.25
A2	0.053	0.069	1.35	1.75
B	0.012	0.020	0.31	0.51
C	0.004	0.01	0.10	0.25
D	0.186	0.202	4.72	5.12
E	0.148	0.164	3.75	4.15
e	0.050 BSC		1.27 BSC	
H	0.224	0.248	5.70	6.30
L	0.012	0.028	0.30	0.70
□	0°	8°	0°	8°

8-Pin TSSOP



	Dimensions in inches		Dimensions in millimeters	
Symbol	**Min**	**Max**	**Min**	**Max**
A	0.047			1.10
A1	0.002	0.006	0.05	0.15
A2	0.031	0.041	0.80	1.05
B	0.007	0.012	0.19	0.30
C	0.004	0.008	0.09	0.20
D	0.114	0.122	2.90	3.10
E	0.169	0.177	4.30	4.50
e	0.026 BSC		0.65 BSC	
H	0.244	0.260	6.20	6.60
L	0.018	0.030	0.45	0.75
θ	0°	8°	0°	8°

Ordering Codes

Ordering Number	Marking	Package Type	Quantity per reel	Temperature
AS80M2180-08ST	AS80M2180	8-pin SOIC, tube		0° C to 70°C
AS80M2180-08SR	AS80M2180	8-pin SOIC, tape and reel	2500	0° C to 70°C
AS80M2180-08TT	AS80M2180	8-pin TSSOP, tube		0° C to 70°C
AS80M2180-08TR	AS80M2180	8-pin TSSOP, tape and reel	2500	0° C to 70°C

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Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to Alliance Semiconductor, dated 11-11-2003